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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR

2SK3480

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3480 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance:

 $R_{DS(on)1} = 31 \text{ m}\Omega \text{ MAX. (VGS} = 10 \text{ V, ID} = 25 \text{ A})$ $R_{DS(on)2} = 36 \text{ m}\Omega \text{ MAX. (VGS} = 4.5 \text{ V, ID} = 25 \text{ A})$

- Low Ciss: Ciss = 3600 pF TYP.
- Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3480	TO-220AB
2SK3480-S	TO-262
2SK3480-ZJ	TO-263
2SK3480-Z	TO-220SMD ^{Note}

Note TO-220SMD package is produced only in Japan.

(TO-220AB)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	100	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±50	Α
Drain Current (pulse) Note1	ID(pulse)	±100	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	84	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	34	Α
Single Avalanche Energy Note2	Eas	116	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V



(TO-262)



(TO-263, TO-220SMD)

THERMAL RESISTANCE

Channel to Case	Rth(ch-C)	1.48	°C/W
Channel to Ambient	Rth(ch-A)	83.3	°C/W



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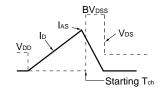


ELECTRICAL CHARACTERISTICS (TA = 25°C)

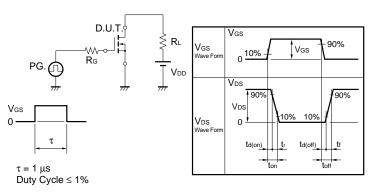
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 100 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 25 A	17	34		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 25 A		25	31	mΩ
	RDS(on)2	Vgs = 4.5 V, ID = 25 A		27	36	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		3600		pF
Output Capacitance	Coss	V _G s = 0 V		360		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		190		pF
Turn-on Delay Time	t d(on)	V _{DD} = 50 V, I _D = 25 A		15		ns
Rise Time	t r	V _G S = 10 V		11		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 0 \Omega$		68		ns
Fall Time	t f			6.0		ns
Total Gate Charge	Q _G	V _{DD} = 80 V		74		nC
Gate to Source Charge	Qgs	V _G S = 10 V		10		nC
Gate to Drain Charge	Q _{GD}	ID = 50 A		20		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 50 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	I _F = 50 A, V _{GS} = 0 V		70		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		180		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

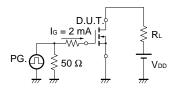
$\begin{array}{c} \text{D.U.T.} \\ \text{Rg} = 25 \ \Omega \\ \text{Vgs} = 20 \rightarrow 0 \ \text{V} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{PG.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \\ \text{\downarrow} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{\downarrow} \\ \text{\downarrow



TEST CIRCUIT 2 SWITCHING TIME

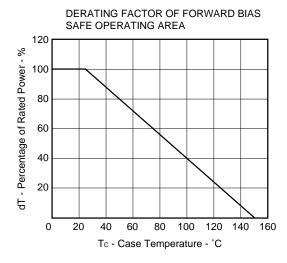


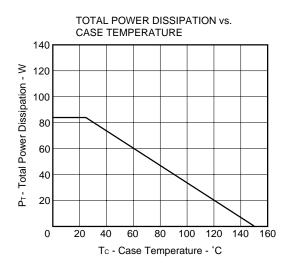
TEST CIRCUIT 3 GATE CHARGE



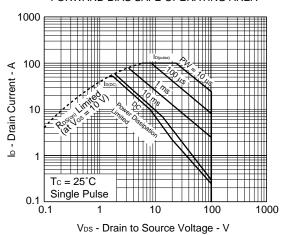


TYPICAL CHARACTERISTICS (TA = 25°C)

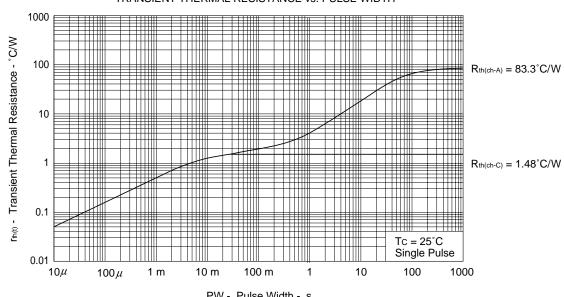




FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

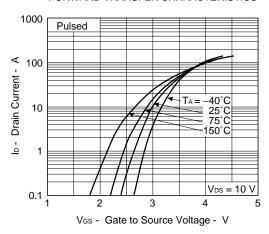


PW - Pulse Width - s

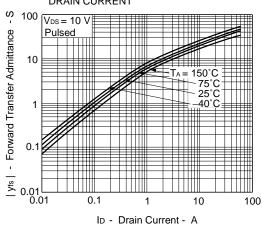
3



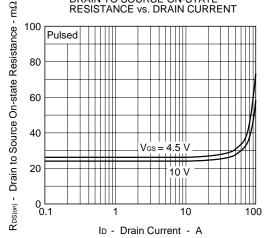
FORWARD TRANSFER CHARACTERISTICS



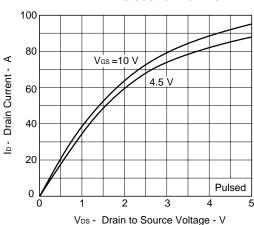
FORWARD TRANSFER ADMITTANCE vs. **DRAIN CURRENT**



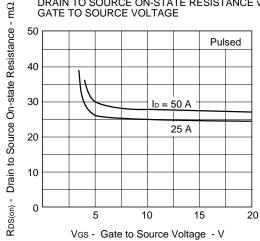
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



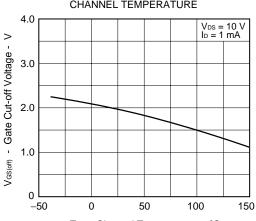
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

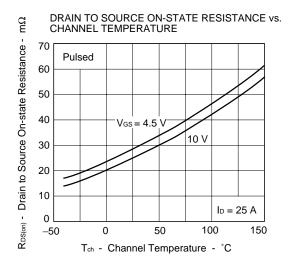


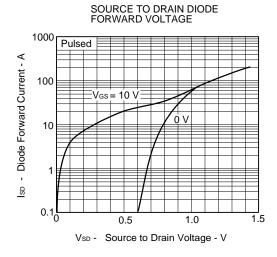
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

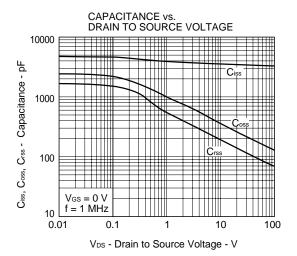


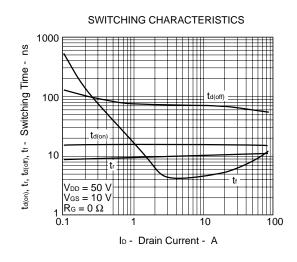
Tch - Channel Temperature - °C

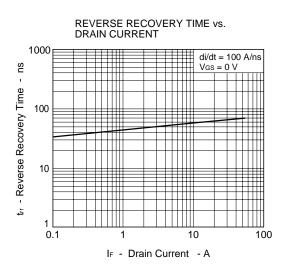


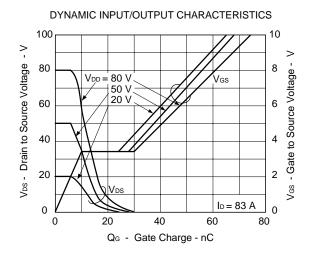


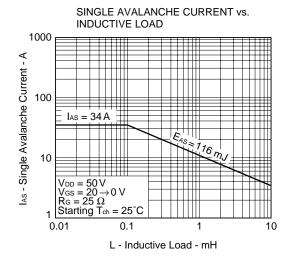


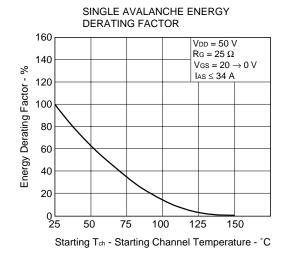








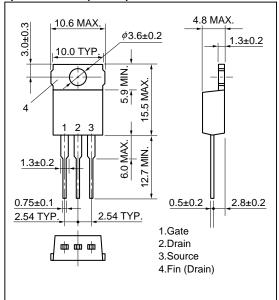




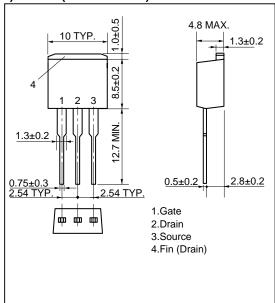


PACKAGE DRAWINGS (Unit: mm)

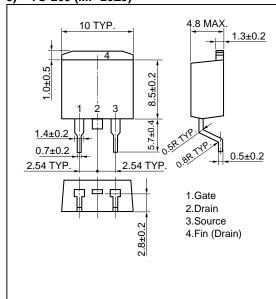
1) TO-220AB(MP-25)



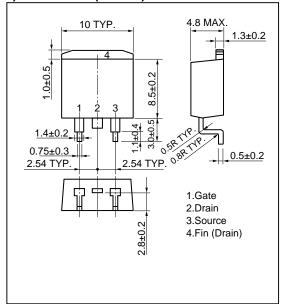
2) TO-262(MP-25 Fin Cut)



3) TO-263 (MP-25ZJ)

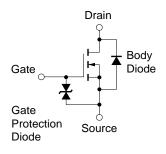


4) TO-220SMD(MP-25Z)^{Note}



EQUIVALENT CIRCUIT

Note This package is produced only in Japan.



Remark

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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